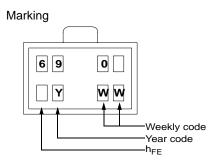


FJC690 NPN Epitaxial Silicon Transistor

Camera Strobe Flash Application

- Complement to FJC790
- High Collector Current
- Low Collector-Emitter Saturation Voltage





Absolute Maximum Ratings $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	45	V
V _{CEO} Collector-Emitter Voltage		45	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	2	A
P _C	Power Dissipation	0.5	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \mu {\rm A}, \ I_{\rm E} = 0$	45			V
BV _{CEO} Collector-Emitter Breakdown Voltage		$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	45			V
BV _{EBO} Emitter-Base Breakdown Voltage		$I_{E} = 100 \mu A, I_{C} = 0$	5			V
I _{CEO}	Collector Cut-off Current	$V_{CE} = 35V, V_{B} = 0$			0.1	μA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			0.1	μA
h _{FE}	DC Current Gain	$V_{CE} = 2V, I_C = 100mA$ $V_{CE} = 2V, I_C = 1mA$ $V_{CE} = 2V, I_C = 2mA$	500 400 150			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_{C} = 0.1A, I_{B} = 0.5mA$ $I_{C} = 1A, I_{B} = 5mA$			80 300	mV mV
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 1A, I _B = 10mA			0.9	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 2V, I_{C} = 1A$			0.85	V
C _{OB}	Collector Output Capacitance	V _{CB} = 10V, I _E = 0, f = 1MHz		20		pF

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July 2007

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
690	FJC690	SOT-89	13"		4,000
		<u> </u>	I	1	

Typical Performance Characteristics

Figure 1. DC current Gain

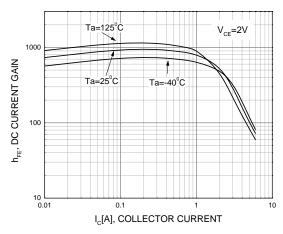


Figure 3. Power Dissipation vs Ambient Temperature

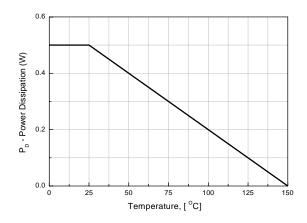
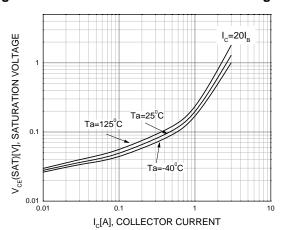
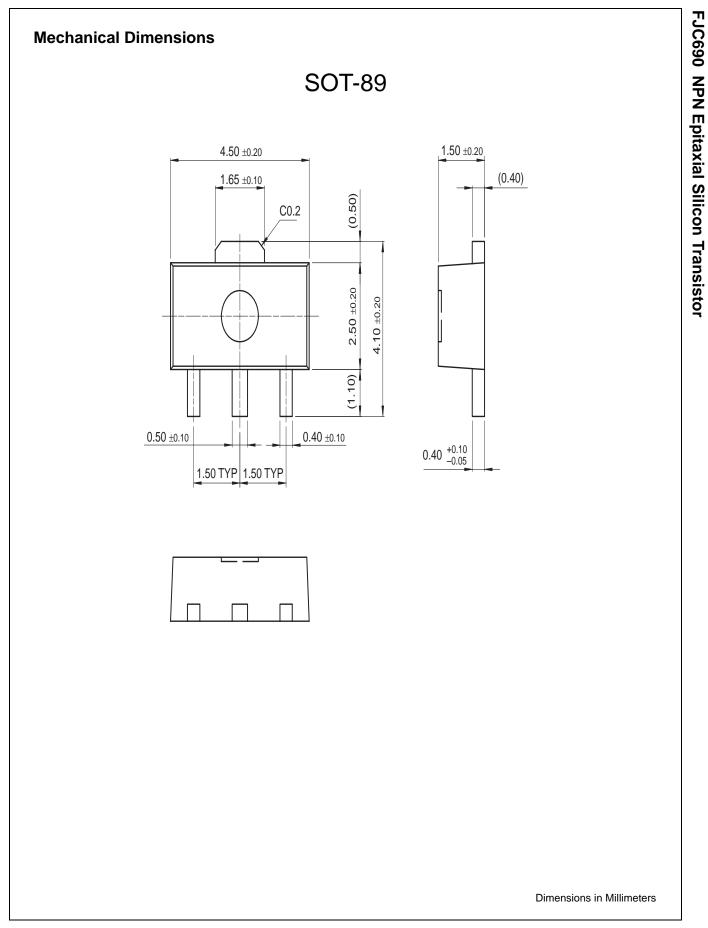


Figure 2. Collector-Emitter Saturation Voltage







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